# A Novel Theoretical Procedure to Determine Absorption and Gain Coefficients in a Symmetric Single Step-Index Quantum Well Laser 

Mustafa TEMİZ, Özgür Önder KARAKILINÇ, Mehmet ÜNAL<br>Pamukkale University, Engineering Faculty, Electrical and Electronics Engineering Department, Kınıklı, Denizli-TURKEY<br>e-mail: mustafatemiz@pau.edu.tr, okarakilinc@pau.edu.tr, mehmetunal@pau.edu.tr


#### Abstract

If the indices $n_{I I}, n_{I, I I I}$ of the regions, the thickness $2 a$ of the active region ( $A R$ ) and the wavelength $\lambda$ for a single symmetric step-index quantum well laser (SSSIQWL) are given, the normalized propagation constant (NPC) $\alpha$ is obtained. In this novel method, absorption and gain coefficients for the SSSIQWL have been obtained in terms of the NPCs $\alpha$ in the even and odd fields, directly.


## 1. Introduction

In double-heterostructure lasers, thickness of the active region (AR) is typically of the order 0.1 to $0.3 \mu \mathrm{~m}$. The thickness $2 a$ of the AR is made smaller in a single quantum well, for example, where $2 a=50-100 \AA[1]$. Because the normalized propagation constant (NPC) $\alpha$ is a structural parameter for material, the probability ratios in this novel method are valid for conventional semiconductor and quantum lasers. Furthermore, this method permits one to calculate a lot of parameters for SSSIQWL [2, 3, 4]. In this work, the absorption and gain coefficients for the SSSIQWL have been obtained in terms of the probability ratios, or NPCs $\alpha$, in the even fields (EF) and odd fields (OF), directly. These are the novelties of this paper.

The notations $\mathrm{n}_{I I}$ and $\mathrm{n}_{I, I I I}$ in Figure 1 are refractive indices of the regions for the SSSIQWL. The relationship between the indices is $n_{I I}>n_{I, I I I}$ for the SSSIQWL. Propagation constants are [2, 3, 4]

$$
\alpha_{I I}^{2}=\left(\frac{\omega n_{I I}}{c}\right)^{2}-\beta_{z}^{2} \text { and } \alpha_{I, I I I}^{2}=\beta_{Z}^{2}-\left(\frac{\omega n_{I, I I I}}{c}\right)^{2}
$$

The carriers are confined in the AR, which is deep between highly thick left and right barriers. The energy states for the carriers in the AR can be described $[2,3,4]$ by the EF and OF, respectively:

$$
\begin{gathered}
E_{y I}=A_{I} \exp \left[\alpha_{I}(x+a)\right] \\
E_{y I I}=A \cos \alpha_{I I} x=A \cos \frac{n \pi x}{2 a}, n=1,3,5, \ldots \\
E_{y I I I}=A_{I I I} \exp \left[-\alpha_{I I I}(x-a)\right]
\end{gathered}
$$

$$
A=\sqrt{\frac{2 \alpha_{I I}}{2 \zeta+\sin 2 \zeta}}, \quad A_{I}=A_{I I I}=A_{I, I I I}=A \cos \zeta
$$

and

$$
\begin{gathered}
e_{y I}=B_{I} \exp \left[\alpha_{I}(x+a)\right], \\
e_{y I I}=B \sin \alpha_{I I} x=B \sin \frac{n \pi x}{2 a}, n=2,4, .6 \ldots, \\
e_{y I I I}=B_{I I I} \exp \left[-\alpha_{I I I}(x-a)\right] \\
B=\sqrt{\frac{2 \alpha_{I I}}{2 \zeta-\sin 2 \zeta}} B_{I}=B_{I I I}=B_{I, I I I}=B \sin \zeta .
\end{gathered}
$$

These fields verify the Schrödinger wave equation $[2,3,4] . \zeta=\alpha_{I I} a, \eta=\alpha_{I, I I I} a$ are parametric variables of the energy eigenvalues of the carriers in the normalized coordinate system $\zeta-\eta, \mathrm{V}=\left(\zeta^{2}+\eta^{2}\right)^{1 / 2}$ is the normalized frequency (NF), NPC is $\alpha=\eta^{2} / \mathrm{V}^{2}=\sin ^{2} \zeta[2,3,4,5]$.


Figure 1. Regions of a SSSIQWL.
A field probability function ratio, $\bar{R}(\bar{r})$, can be defined as the ratio of the total evanescent field function probability $\mathrm{I}_{\ell}\left(\mathrm{I}_{\ell}^{\prime}\right)$, in the region I and III to the active field function probability $\left(\mathrm{I}_{I I}\right)$ in the AR in a SSSIQWL. $\bar{R}(\bar{r})$ is expressed as

$$
\begin{gathered}
\frac{I_{\ell}}{I_{I I}}=\bar{R}=\frac{1-\alpha}{\eta+\alpha}, \\
I_{\ell}=\int_{-\infty}^{-a}\left|E_{y I}(x)\right|^{2} d x+\int_{a}^{\infty}\left|E_{y I I I}(x)\right|^{2} d x \\
I_{I I}=2 \int_{0}^{a}\left|E_{y I I}(x)\right|^{2} d x \\
I_{i}=I_{I I}+I_{\ell}
\end{gathered}
$$

where

$$
\bar{r}=\frac{I_{\ell}^{\prime}}{I_{I I}^{\prime}}=\frac{1-\alpha}{\eta-\alpha}, \quad I_{\ell}^{\prime}=\int_{-\infty}^{-a}\left|e_{y I}(x)\right|^{2} d x+\int_{a}^{\infty}\left|e_{y I I I}(x)\right|^{2} d x, I_{I I}^{\prime}=2 \int_{0}^{a}\left|e_{y I I}(x)\right|^{2} d x, \quad I_{i}^{\prime}=I_{I I}^{\prime}+I_{\ell}^{\prime}
$$

## 2. Some Probability Ratios and Confinement Factors in the SSSIQWL

Representing the confinement factors $\Gamma_{I I}$ and $\Lambda_{I I},[2,3,4,5]$ for the EF and OF in the AR, respectively, the ratios $\bar{K}$ and $\bar{q}$ of the loss probabilities to the input probabilities can be obtained as

$$
\frac{I_{\ell}}{I_{i}}=\bar{K}=\frac{1-\alpha}{\eta+1}=\frac{1}{1+1 / R}=1-\Gamma_{I I}, \quad \frac{I_{\ell}^{\prime}}{I_{i}^{\prime}}=\bar{q}=\frac{1-\alpha}{1+\eta-2 \alpha}=\frac{1}{1+\frac{1}{\bar{r}}}=1-\Lambda_{I I}
$$

respectively; and the confinement factors $\Gamma_{I I}$ and $\Lambda_{I I}$ in the region II are, respectively given by

$$
\Gamma_{I I}=\frac{\alpha+\eta}{1+\eta}=\frac{\bar{K}}{\bar{R}}, \quad \Lambda_{I I}=\frac{\eta-\alpha}{1+\eta-2 \alpha}=\frac{1}{1+\bar{r}}=\frac{\bar{q}}{\bar{r}}
$$

for the EF and OF in the SSSIQWL. Thus, we have the relations [4] $\bar{K}+\Gamma_{I I}=1, \bar{q}+\Lambda_{I I}=1$.

## 3. The Novel Absorption Coefficients and Gain Coefficients for The SSSIQWL

$\mathrm{F}_{I}$ (respectively, $F_{I}^{\prime}$ ), $\mathrm{F}_{I I}\left(F_{I I}^{\prime}\right)$ and $\mathrm{F}_{I I I}\left(F_{I I I}^{\prime}\right)$ represent the confinement factors of regions I, II and III for the even (odd) field. The parameter $g$ (respectively, $g^{\prime}$ ) is the gain coefficient, which is described by the structural properties of the SSSIQWL for the EF (OF). We can define absorption coefficients by $k_{1}, k_{3}$ ( $k_{1}^{\prime}$, $\left.k_{3}^{\prime}\right)$ in the ASSIQWL or $k_{1,3}\left(k_{1,3}^{\prime}\right)$ in the SSSIQWL, in the EF (OF) in regions I and III. Bhattacharya [1] gives $k_{1} F_{I}+k_{3} F_{I I I}=g F_{I I}, k_{1}^{\prime} F_{I}^{\prime}+k_{3}^{\prime} F_{I I I}^{\prime}=g^{\prime} F_{I I}^{\prime}$, where $g F_{I I}\left(g^{\prime} F_{I I}^{\prime}\right)$ is called the modal gain for the $\mathrm{EF}(\mathrm{OF})$. These modal gains are obtained as $g \Gamma_{I I}=\left(1-\Gamma_{I I}\right) k_{1,3}=\bar{K} k_{1,3}, g^{\prime} \Lambda_{I I}=\left(1-\Lambda_{I I}\right) k_{1,3}^{\prime}=\bar{q}_{1,3}^{\prime}$ [1]. So, the novel expressions in this paper for absorption and amplification gain coefficients and their ratios become, respectively,

$$
\begin{gathered}
k_{1,3}=\frac{\ln G}{\bar{K} \ell_{g}}, \quad k_{1,3}^{\prime}=\frac{\ln G^{\prime}}{\bar{q} \ell_{g}}, \quad-k_{2}=g=\frac{\ln G}{\ell_{g} \Gamma_{I I}}, \quad-k_{2}^{\prime}=g^{\prime}=\frac{\ln G^{\prime}}{\ell_{g} \Lambda_{I I}} \\
\frac{g}{k_{1,3}}=\frac{\bar{K}}{\Gamma_{I I}}=\bar{R}, \quad \frac{g}{g^{\prime}}=\frac{\Lambda_{I I}}{\Gamma_{I I}}, \quad \frac{g^{\prime}}{k_{13}^{\prime}}=\frac{\bar{q}}{\Lambda_{I I}}=\bar{r}, \quad \frac{k_{1,3}}{k_{1,3}^{\prime}}=\frac{\bar{q}}{\bar{K}}
\end{gathered}
$$

for the even and odd fields in the same power gain $\left(G=G^{\prime}\right)$, respectively. Here, $G$ and $G^{\prime}$ are power gains of AR of the SSSIQWL for the EF and OF [1].

For example, for $\lambda=0.5145 \times 10^{-6} \mathrm{~m}, \mathrm{n}_{I, I I I}=1.55, \mathrm{n}_{I I}=1.57$ and $2 a=1 \mu \mathrm{~m}=10000 \AA$ in the SSSIQWL, we have $\mathrm{V}=3.0506106640935, \alpha=0.851569419263456, \alpha_{I I}=2.350598599618280 \times 10^{6}$ $\mathrm{m}^{-1}, \zeta=1.17529929980914, \eta=2.81511935444115, \alpha_{I, I I I}=5.630238708882300 \times 10^{6} \mathrm{~m}^{-1}, \beta_{z}=$ $1.939187568094921 \times 10^{7} \mathrm{~m}^{-1}, \bar{K}=0.03890588129668, \bar{R}=0.04048082340694, \Gamma_{I I}=0.96109411870332$, $\mathrm{g} / \mathrm{k}_{1,3}=\bar{R}$. For given $\ell_{g}=0.05 \mathrm{~m}$ and $\mathrm{G}=5000$ we have $\mathrm{g}=1.772395236984149 \times 10^{2} \mathrm{~m}^{-1}$ and $\mathrm{k}_{1,3}$ $=4.378357671154261 \times 10^{3} \mathrm{~m}^{-1}$. Note that our result for the NF V is more sensitive than the NF in ref. [6], in which NPC had been defined differently from our definition of $\alpha$. Since $\zeta<1.57$ in this example, there are no solutions for the OF and its related parameters, such as $\bar{q}$ and $\Lambda_{I I}$ [5]. Consequently, we are able to calculate absorption and amplification gain coefficients in terms of NPC $\alpha$ for given indices $\mathrm{n}_{I I}$, $\mathrm{n}_{I, I I I}$, the thickness $2 a$ of the AR and the wavelength $\lambda$ for the EF and OF in the SSSIQWL.

## References

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